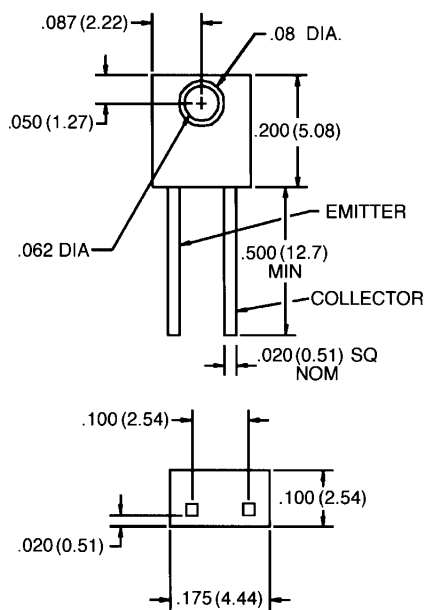




## SIDELOOKER PHOTOTRANSISTOR

**QSE113/114**

### PACKAGE DIMENSIONS



ST2148

#### NOTES:

1. DIMENSIONS ARE IN INCHES (mm).
2. TOLERANCE IS  $\pm .010$  (.25) UNLESS OTHERWISE SPECIFIED.

### DESCRIPTION

The QSE11X family is a silicon phototransistor encapsulated in a wide angle, infrared transparent, dark blue, plastic sidelooker shell package.

### FEATURES

- Tight production distribution with min/max limits.
- Steel lead frames for improved reliability in solder mounting.
- Good optical-to-mechanical alignment.
- Plastic package is infrared transparent and tinted to attenuate visible light.
- Mechanically and spectrally matched to the QEE113 and QEE123 LEDs.
- Dark blue shell body allows easy recognition from LED.



## SIDELOOKER PHOTOTRANSISTOR

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

Storage Temperature	-40°C to + 100°C
Operating Temperature	-40°C to + 100°C
Soldering:	
Lead Temperature (Iron)	240°C for 5 sec. <sup>(2,3,4,5)</sup>
Lead Temperature (Flow)	260°C for 10 sec. <sup>(2,3,5)</sup>
Collector-Emitter Breakdown Voltage	30 Volts
Emitter-Collector Breakdown Voltage	5.0 Volts
Power Dissipation	100 mW <sup>(1)</sup>

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

(All measurements made under pulse conditions.)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Collector-Emitter Breakdown	$BV_{CEO}$	30	—	—	V	$I_C = 1\text{ mA}$
Emitter-Collector Breakdown	$BV_{ECO}$	5.0	—	—	V	$I_E = 100\ \mu\text{A}$
Collector-Emitter Leakage	$I_{CEO}$	—	—	100	nA	$V_{CE} = 10\text{ V}$
Reception Angle at 1/2 Sensitivity	$\theta$	—	$\pm 25$	—	Degrees	
On-State Collector Current QSE113	$I_{C(ON)}$	0.25	—	1.5	mA	$E_e = 0.5\text{ mW/cm}^2$ , $V_{CE} = 5\text{V}^{(6)}$
On-State Collector Current QSE114	$I_{C(ON)}$	1.0	—	—	mA	$E_e = 0.5\text{ mW/cm}^2$ , $V_{CE} = 5\text{V}^{(6)}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	0.4	V	$I_C = 0.4\text{ mA}$ , $E_e = 0.5\text{mW/cm}^2^{(6)}$
Rise Time	$t_r$	—	8.0	—	$\mu\text{S}$	$I_C = .15\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 100\Omega$
Fall Time	$t_f$	—	8.0	—	$\mu\text{S}$	$I_C = .15\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 100\Omega$

### NOTES

1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
2. RMA flux is recommended.
3. Methanol or Isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron tip 1/16" (1.6 mm) minimum from housing.
5. As long as leads are not under any stress or spring tension.
6. Light source is an AlGaAs LED emitting light at a peak wavelength of 880 nm.